

MOSFETs Silicon Carbide N-Channel MOS

## TW083U65C

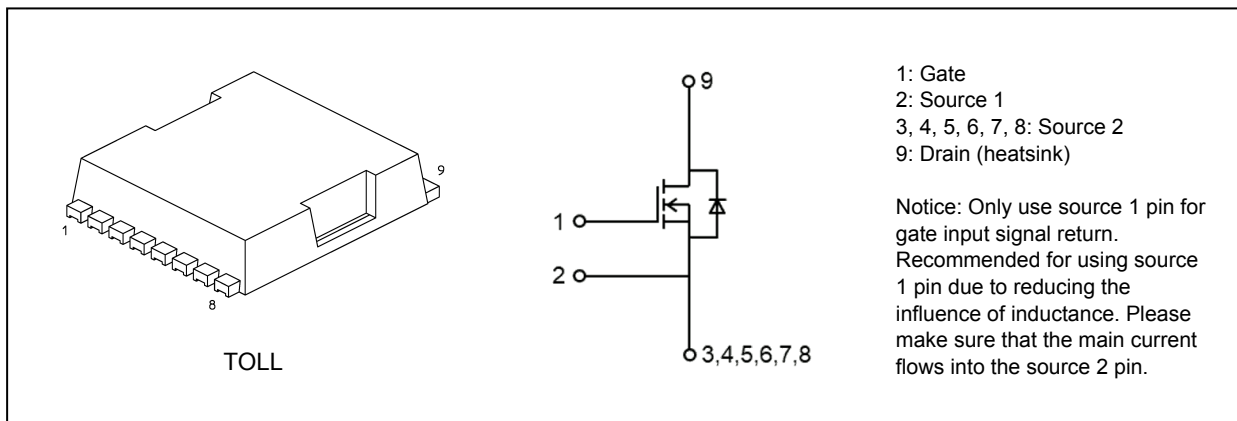
### 1. Applications

- Switching Voltage Regulators

### 2. Features

- (1) Chip design of 3rd generation (Built-in SiC schottky barrier diode)
- (2) Low diode forward voltage:  $V_{DSF} = -1.35 \text{ V}$  (typ.)
- (3) High voltage:  $V_{DSS} = 650 \text{ V}$
- (4) Low drain-source on-resistance:  $R_{DS(ON)} = 83 \text{ m}\Omega$  (typ.)
- (5) Less susceptible to malfunction due to high threshold voltage:  $V_{th} = 3.0 \text{ to } 5.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 0.6 \text{ mA}$ )
- (6) Recommended gate - source drive voltage:  $V_{GS_{on}} = 18 \text{ V}$ ,  $V_{GS_{off}} = 0 \text{ V}$
- (7) Enhancement mode.

### 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics   | Symbol    | Rating     | Unit             |
|---|-----------|------------|------------------|
| Drain-source voltage  | $V_{DSS}$ | 650        | V                |
| Gate-source voltage   | $V_{GSS}$ | +25/-10    |                  |
| Drain current (DC) ( $T_c = 25\text{ }^\circ\text{C}$ ) (Note 1)      | $I_D$     | 28         | A                |
| Drain current (DC) ( $T_c = 100\text{ }^\circ\text{C}$ ) (Note 1)     | $I_D$     | 20         |                  |
| Drain current (pulsed) ( $T_c = 25\text{ }^\circ\text{C}$ ) (Note 1)  | $I_{DP}$  | 66         |                  |
| Drain current (pulsed) ( $T_c = 100\text{ }^\circ\text{C}$ ) (Note 1) | $I_{DP}$  | 52         |                  |
| Power dissipation ( $T_c = 25\text{ }^\circ\text{C}$ )                | $P_D$     | 111        | W                |
| Channel temperature   | $T_{ch}$  | 175        | $^\circ\text{C}$ |
| Storage temperature   | $T_{stg}$ | -55 to 175 |                  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## 5. Thermal Characteristics

| Characteristics                    | Symbol         | Max   | Unit                      |
|------------------------------------|----------------|-------|---------------------------|
| Channel-to-case thermal resistance | $R_{th(ch-c)}$ | 1.350 | $^\circ\text{C}/\text{W}$ |

Note 1: Ensure that the channel temperature does not exceed  $175\text{ }^\circ\text{C}$ .

Note: This transistor is sensitive to electrostatic discharge and should be handled with care. It should be used for switching applications.

## 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                 | Symbol        | Test Condition   | Min | Typ. | Max       | Unit          |
|---------------------------------|---------------|--|-----|------|-----------|---------------|
| Gate leakage current            | $I_{GSS}$     | $V_{GS} = +25/-10\text{ V}, V_{DS} = 0\text{ V}$                                   | —   | —    | $\pm 0.1$ | $\mu\text{A}$ |
| Drain cut-off current           | $I_{DSS}$     | $V_{DS} = 650\text{ V}, V_{GS} = 0\text{ V}$                                       | —   | 2.8  | 37        |               |
|                                 |               | $T_a = 150\text{ }^\circ\text{C},$<br>$V_{DS} = 650\text{ V}, V_{GS} = 0\text{ V}$ | —   | 14   | —         |               |
| Drain-source breakdown voltage  | $V_{(BR)DSS}$ | $I_D = 4\text{ mA}, V_{GS} = 0\text{ V}$   | 650 | —    | —         | V             |
| Gate threshold voltage (Note 2) | $V_{th}$      | $V_{DS} = 10\text{ V}, I_D = 0.6\text{ mA}$  | 3.0 | —    | 5.0       |               |
| Drain-source on-resistance      | $R_{DS(ON)}$  | $V_{GS} = 18\text{ V}, I_D = 15\text{ A}$  | —   | 83   | 124       | m $\Omega$    |
|                                 |               | $T_a = 150\text{ }^\circ\text{C},$<br>$V_{GS} = 18\text{ V}, I_D = 15\text{ A}$    | —   | 89   | —         |               |

Note 2: Please be sure to apply  $I_{GSS}$  ( $V_{GS} = 25\text{ V}$ ) before the  $V_{th}$  test.

## 6.2. Dynamic Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                               | Symbol       | Test Condition  | Min | Typ. | Max           | Unit     |
|---|--------------|---|-----|------|---------------|----------|
| Input capacitance                             | $C_{iss}$    | $V_{DS} = 400\text{ V}, V_{GS} = 0\text{ V},$<br>$f = 100\text{ kHz}$ | —   | 873  | —             | pF       |
| Reverse transfer capacitance                  | $C_{rss}$    |   | —   | 3.4  | —             |          |
| Output capacitance                            | $C_{oss}$    |   | —   | 110  | —             |          |
| Effective output capacitance (energy related) | $C_{o(er)}$  |   | —   | 125  | —             |          |
| Effective output capacitance (time related)   | $C_{o(tr)}$  |   | —   | 180  | —             |          |
| Output charge                                 | $Q_{oss}$    |   | —   | 72   | —             |          |
| $C_{oss}$ stored energy                       | $E_{oss}$    | —   | 10  | —    | $\mu\text{J}$ |          |
| Gate resistance                               | $r_g$        | $V_{DS} = \text{OPEN}, f = 1\text{ MHz}$                              | —   | 4.4  | —             | $\Omega$ |
| Turn-on delay time                            | $t_{d(on)}$  | See Fig. 6.2.1  | —   | 21   | —             | ns       |
| Switching time (rise time)                    | $t_r$        |   | —   | 14   | —             |          |
| Turn-off delay time                           | $t_{d(off)}$ |   | —   | 28   | —             |          |
| Switching time (fall time)                    | $t_f$        |   | —   | 14   | —             |          |
| Turn-on switching loss                        | $E_{on}$     |   | —   | 98   | —             |          |
| Turn-off switching loss                       | $E_{off}$    | —   | 38  | —    | $\mu\text{J}$ |          |

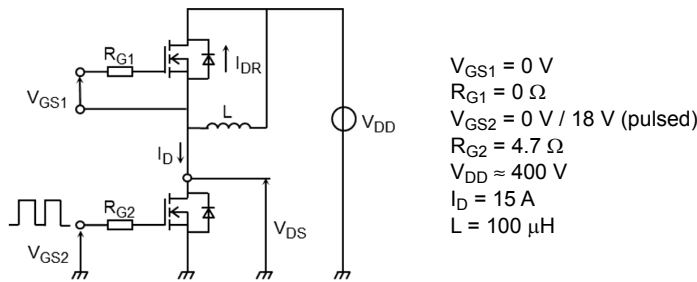


Fig. 6.2.1 Switching Time Test Circuit

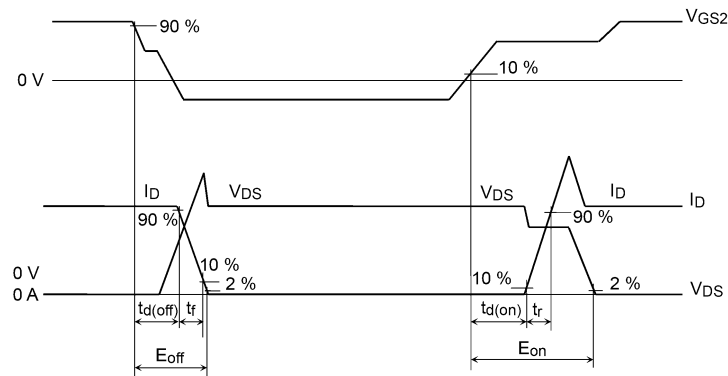


Fig. 6.2.2 Timing Diagrams

### 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

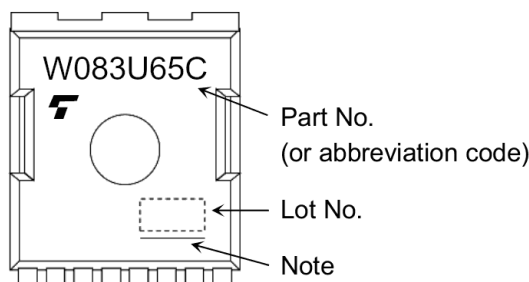
| Characteristics                                 | Symbol    | Test Condition  | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | $Q_g$     | $V_{DD} \approx 400\text{ V}$ , $V_{GS} = 18\text{ V}$ ,<br>$I_D = 15\text{ A}$ | —   | 28   | —   | nC   |
| Gate-source charge 1                            | $Q_{gs1}$ |   | —   | 14   | —   |      |
| Gate-drain charge                               | $Q_{gd}$  |   | —   | 3.9  | —   |      |

### 6.4. Source · Drain Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                         | Symbol    | Test Condition  | Min | Typ.  | Max   | Unit |
|---|-----------|---|-----|-------|-------|------|
| Reverse drain current (DC) (Note 3)     | $I_{DR}$  | $T_c = 25\text{ }^\circ\text{C}$ , $V_{GS} = -5\text{ V}$   | —   | —     | 26    | A    |
|   |           | $T_c = 100\text{ }^\circ\text{C}$ , $V_{GS} = -5\text{ V}$  | —   | —     | 17    |      |
|   |           | $T_c = 25\text{ }^\circ\text{C}$ , $V_{GS} = 18\text{ V}$   | —   | —     | 28    |      |
|   |           | $T_c = 100\text{ }^\circ\text{C}$ , $V_{GS} = 18\text{ V}$  | —   | —     | 20    |      |
| Reverse drain current (pulsed) (Note 3) | $I_{DRP}$ | $T_c = 25\text{ }^\circ\text{C}$ , $V_{GS} = -5\text{ V}$   | —   | —     | 66    |      |
|   |           | $T_c = 100\text{ }^\circ\text{C}$ , $V_{GS} = -5\text{ V}$  | —   | —     | 29    |      |
|   |           | $T_c = 25\text{ }^\circ\text{C}$ , $V_{GS} = 18\text{ V}$   | —   | —     | 66    |      |
|   |           | $T_c = 100\text{ }^\circ\text{C}$ , $V_{GS} = 18\text{ V}$  | —   | —     | 52    |      |
| Diode forward voltage                   | $V_{DSF}$ | $I_{DR} = 8\text{ A}$ , $V_{GS} = -5\text{ V}$  | —   | -1.35 | -1.80 | V    |
|   |           | $T_a = 150\text{ }^\circ\text{C}$ ,<br>$I_{DR} = 8\text{ A}$ , $V_{GS} = -5\text{ V}$                                   | —   | -1.57 | —     |      |
| Reverse recovery time                   | $t_{rr}$  | $I_{DR} = 10\text{ A}$ , $V_{GS} = 0\text{ V}$ ,<br>$V_{DD} = 400\text{ V}$ , $-dI_{DR}/dt = 1000\text{ A}/\mu\text{s}$ | —   | 45    | —     | ns   |
| Reverse recovery charge                 | $Q_{rr}$  |   | —   | 189   | —     | nC   |
| Peak reverse recovery current           | $I_{rr}$  |   | —   | 8.4   | —     | A    |

Note 3: Ensure that the channel temperature does not exceed  $175\text{ }^\circ\text{C}$ .

## 7. Marking (Note)



**Fig. 7.1 Marking**

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

## 8. Characteristics Curves (Note)

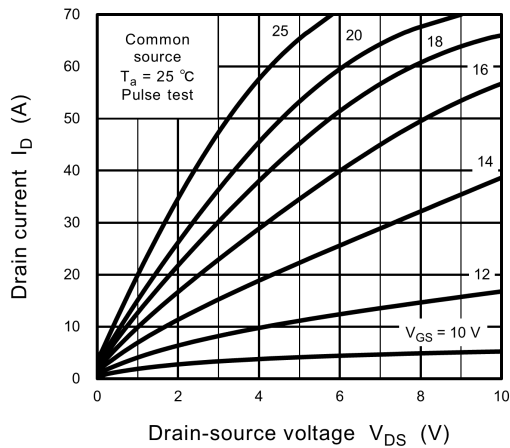


Fig. 8.1  $I_D - V_{DS}$

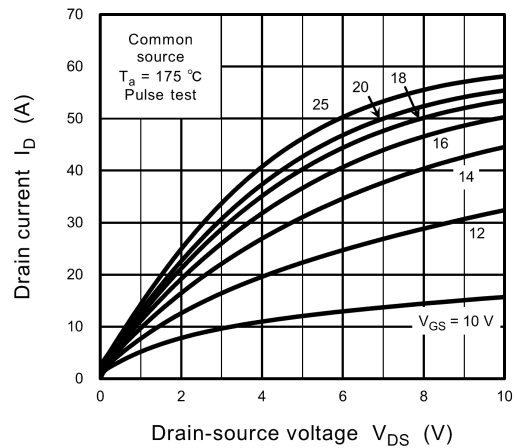


Fig. 8.2  $I_D - V_{DS}$

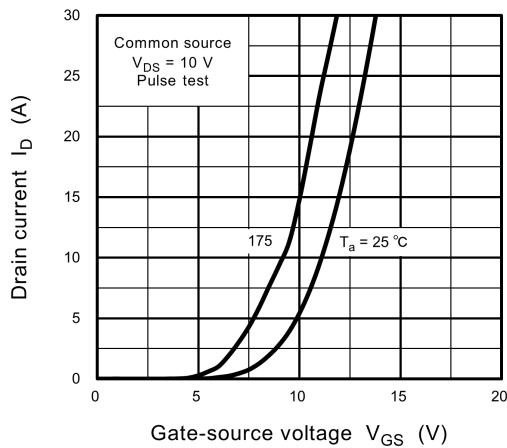


Fig. 8.3  $I_D - V_{GS}$

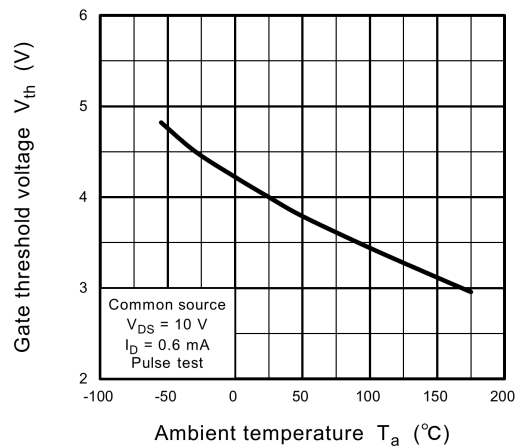


Fig. 8.4  $V_{th} - T_a$

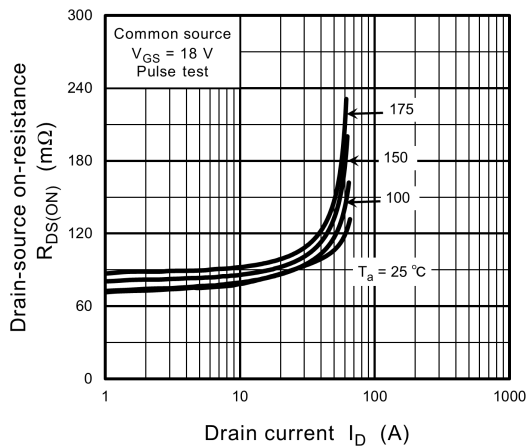


Fig. 8.5  $R_{DS(ON)} - I_D$

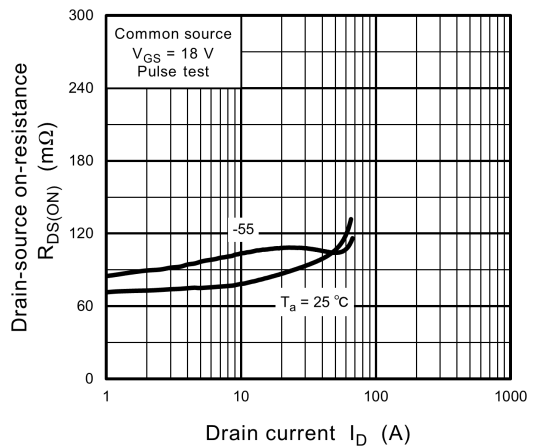
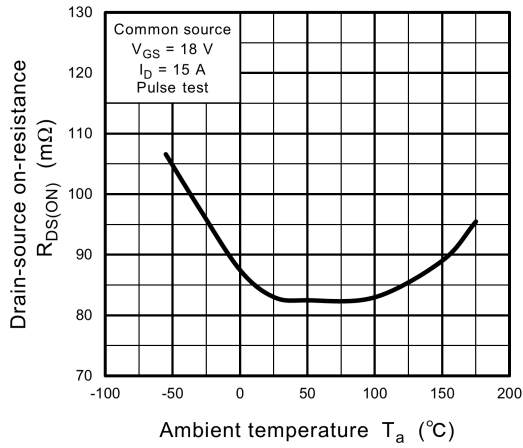
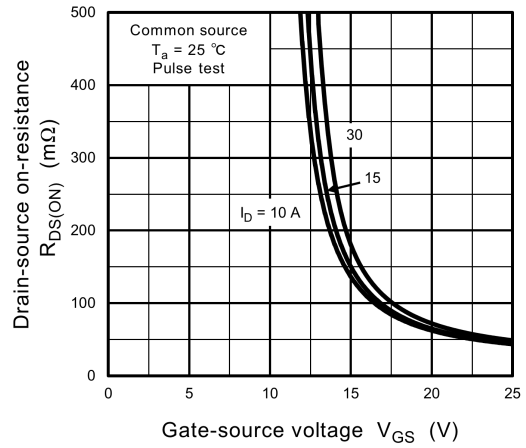


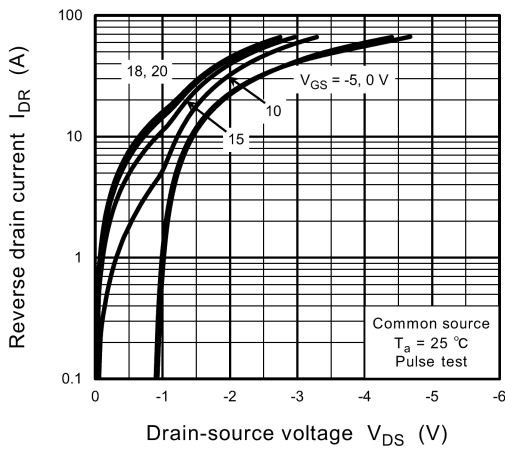
Fig. 8.6  $R_{DS(ON)} - I_D$



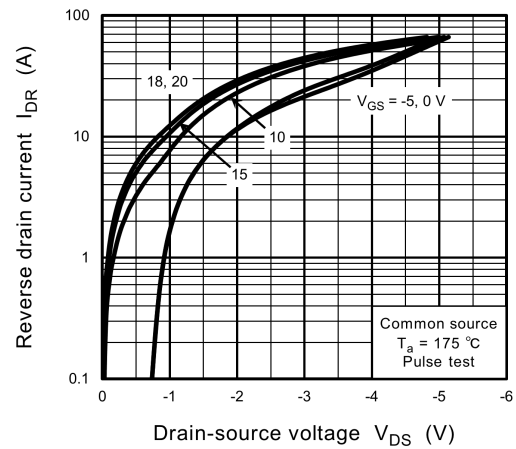
**Fig. 8.7  $R_{DS(ON)} - T_a$**



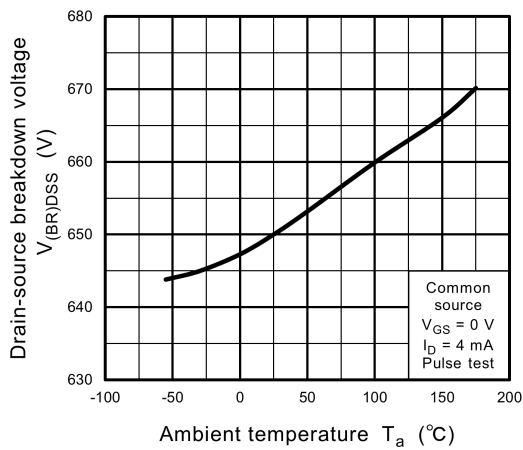
**Fig. 8.8  $R_{DS(ON)} - V_{GS}$**



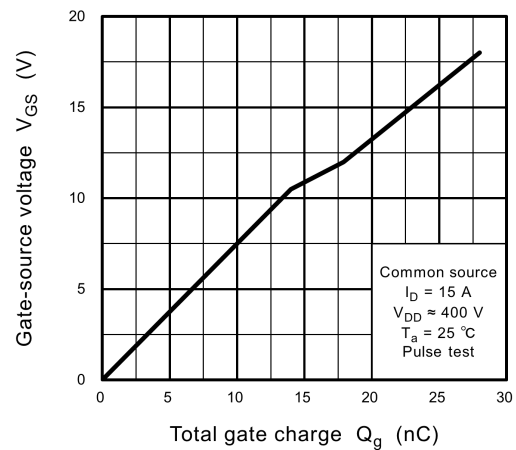
**Fig. 8.9  $I_{DR} - V_{DS}$**



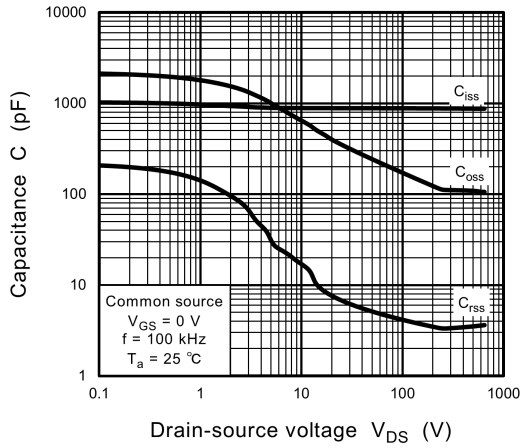
**Fig. 8.10  $I_{DR} - V_{DS}$**



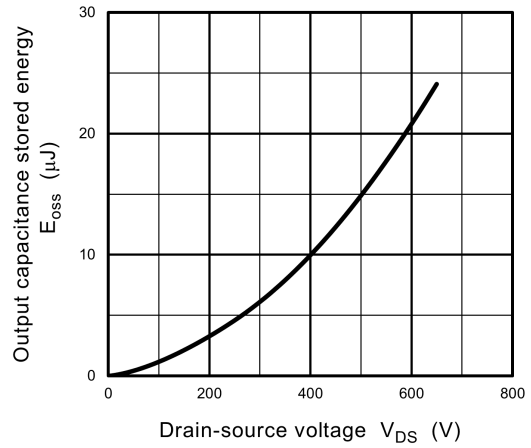
**Fig. 8.11  $V_{(BR)DSS} - T_a$**



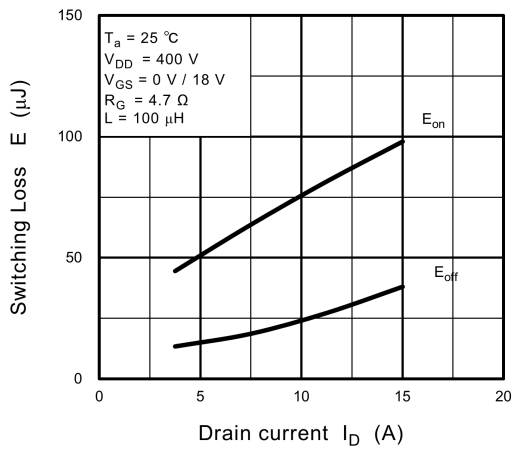
**Fig. 8.12 Dynamic Input Characteristics**



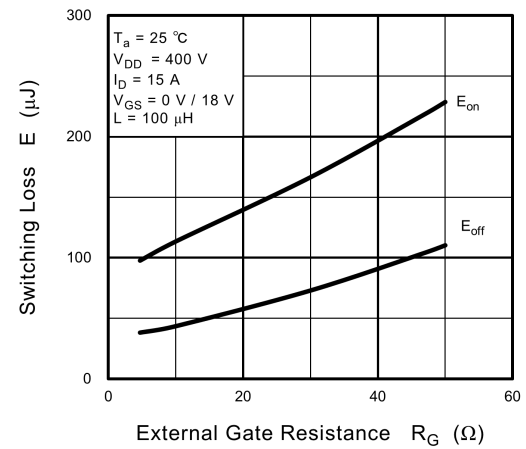
**Fig. 8.13 C - V<sub>DS</sub>**



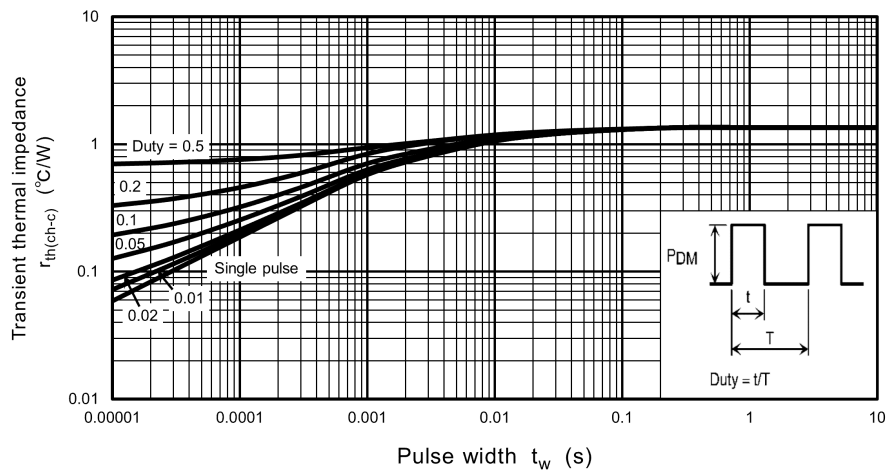
**Fig. 8.14 E<sub>oss</sub> - V<sub>DS</sub>**



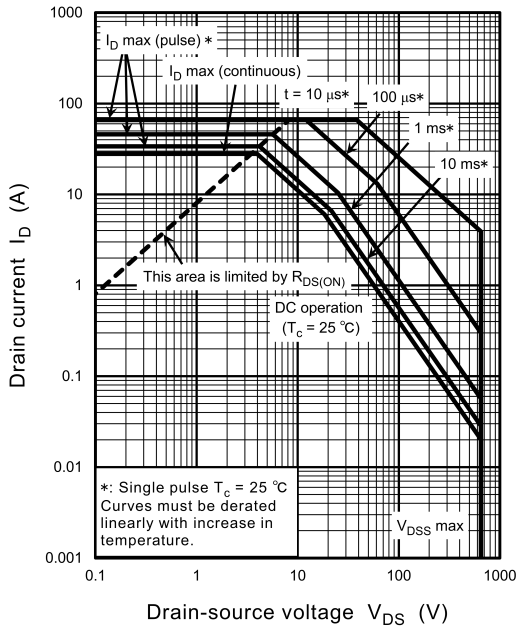
**Fig. 8.15 E - I<sub>D</sub>**



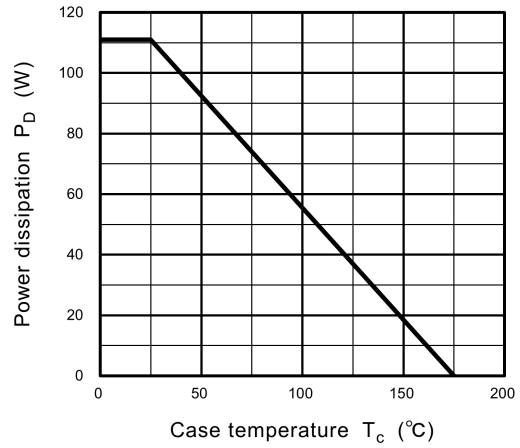
**Fig. 8.16 E - R<sub>G</sub>**



**Fig. 8.17 r<sub>th(ch-c)</sub> - t<sub>w</sub>  
(Guaranteed Maximum)**



**Fig. 8.18 Safe Operating Area (Guaranteed Maximum)**

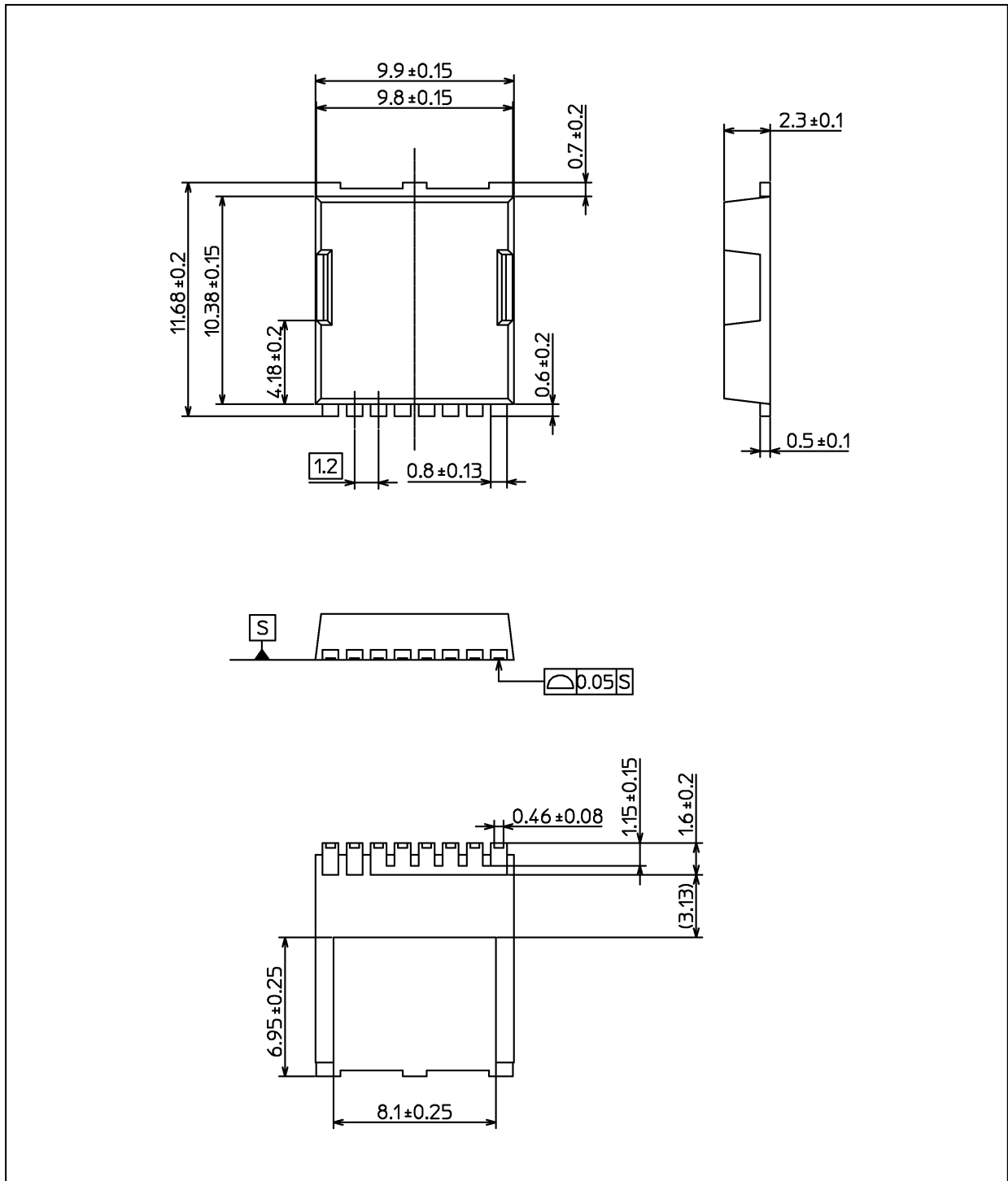


**Fig. 8.19  $P_D - T_c$  (Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Package Dimensions

Unit: mm



Weight: 0.75 g (typ.)

|                   |
|-------------------|
| Package Name(s)   |
| TOSHIBA: 2-10AF1A |
| Nickname: TOLL    |

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